

CMOS Digital Integrated Circuits Silicon Monolithic

TC7SET08F

1. Functional Description

· 2-Input AND Gate

2. Features

- (1) AEC-Q100 (Rev. H) (Note 1)
- (2) Wide operating temperature range: $T_{opr} = -40$ to 125 °C (Note 2)
- (3) High speed operation: $t_{pd} = 4.2 \text{ ns (typ.)}$ ($V_{CC} = 5.0 \text{ V}$, $C_L = 15 \text{ pF}$)
- (4) Low power dissipation: $I_{CC} = 2.0 \mu A \text{ (max)} \text{ (}T_a = 25 \text{ °C)}$
- (5) Compatible with TTL outputs: $V_{IL} = 0.8 \text{ V (max)}$

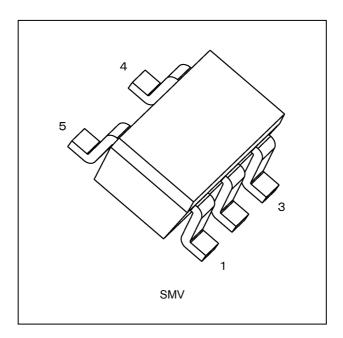
$$V_{IH} = 2.0 \text{ V (min)}$$

- (6) 5.5 V tolerant inputs
- (7) Balanced Propagation Delay: t_{PLH} ≈ t_{PHL}

Note 1: This device is compliant with the reliability requirements of AEC-Q100. For details, contact your Toshiba sales representative.

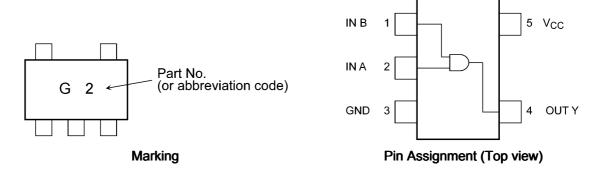
Note 2: For devices with the ordering part number ending in J(CT. T_{opr} = -40 to 85 °C for the other devices.

3. Packaging





4. Marking and Pin Assignment



5. IEC Logic Symbol



6. Truth Table

А	В	Y
L	L	L
L	Н	L
Н	L	L
Н	Н	Н

7. Absolute Maximum Ratings (Note) (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V _{CC}		-0.5 to 7.0	V
Input voltage	V _{IN}		-0.5 to 7.0	
DC output voltage	V _{OUT}		-0.5 to V _{CC} + 0.5	
Input diode current	I _{IK}		-20	mA
Output diode current	I _{OK}	(Note 1)	±20	
DC output current	l _{out}		±25	
V _{CC} /ground current	I _{CC}		±50	
Power dissipation	P_D		200	mW
Storage temperature	T _{stg}		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: V_{OUT} < GND, V_{OUT} > V_{CC}



8. Operating Ranges (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V _{CC}		4.5 to 5.5	V
Input voltage	V _{IN}		0 to 5.5	
Output voltage	V _{OUT}		0 to V _{CC}	
Operating temperature	T _{opr}	(Note 1)	-40 to 125	°C
		(Note 2)	-40 to 85	
Input rise and fall time	dt/dv		0 to 20	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either V_{CC} or GND.

Note 1: For devices with the ordering part number ending in J(CT.

Note 2: For devices except those with the ordering part number ending in J(CT.

9. Electrical Characteristics

9.1. DC Characteristics (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Min	Тур.	Max	Unit
High-level input voltage	V _{IH}	_		4.5 to 5.5	2.0	_	_	V
Low-level input voltage	V _{IL}	_		4.5 to 5.5	_		0.8	V
High-level output voltage	V _{OH}	V _{IN} = V _{IH}	I _{OH} = -50 μA	4.5	4.4	4.5	_	V
			I _{OH} = -8 mA	4.5	3.94	_	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	4.5	_	0.0	0.1	V
			I _{OL} = 8 mA	4.5	_	_	0.36	
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND	V _{IN} = 5.5 V or GND		_	_	±0.1	μΑ
Quiescent supply current	Icc	V _{IN} = V _{CC} or GND		5.5	_		2.0	μΑ
	I _{CCT}	Per input: V _{IN} = 3.4 V Other input: V _{CC} or GND		5.5	_		1.35	mA

9.2. DC Characteristics (Unless otherwise specified, T_a = -40 to 85 °C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit	
High-level input voltage	V _{IH}	_		4.5 to 5.5	2.0	_	V
Low-level input voltage	V _{IL}	_		4.5 to 5.5	_	0.8	V
High-level output voltage	V _{OH}	V _{IN} = V _{IH}	I _{OH} = -50 μA	4.5	4.4	_	V
			I_{OH} = -8 mA	4.5	3.80	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	4.5	_	0.1	V
			I _{OL} = 8 mA	4.5	_	0.44	
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_	±1.0	μА
Quiescent supply current	Icc	V _{IN} = V _{CC} or GND		5.5	_	20.0	μА
	I _{CCT}	Per input: V _{IN} = 3.4 V Other input: V _{CC} or GND		5.5	_	1.50	mA



9.3. DC Characteristics (Note) (Unless otherwise specified, T_a = -40 to 125 °C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit	
High-level input voltage	V _{IH}	_		4.5 to 5.5	2.0	_	V
Low-level input voltage	V _{IL}	_		4.5 to 5.5	_	0.8	V
High-level output voltage	V _{OH}	$V_{IN} = V_{IH}$	I _{OH} = -50 μA	4.5	4.4		V
			I _{OH} = -8 mA	4.5	3.70	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	4.5	_	0.1	V
			I _{OL} = 8 mA	4.5		0.55	
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_	±2.0	μА
Quiescent supply current	Icc	V _{IN} = V _{CC} or GND		5.5		40.0	μΑ
	I _{CCT}	Per input: V _{IN} = 3.4 V Other input: V _{CC} or GND		5.5		1.50	mA

Note: For devices with the ordering part number ending in J(CT.



9.4. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Unit
Propagation delay time	t _{PLH} ,t _{PHL}		_	5.0 ± 0.5	15	_	4.2	6.2	ns
					50	_	6.5	9.0	
Input capacitance	C _{IN}		_			_	4	10	pF
Power dissipation capacitance	C _{PD}	(Note 1)	_			_	17		pF

Note 1: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation. $I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

9.5. AC Characteristics

(Unless otherwise specified, T_a = -40 to 85 °C, Input: t_r = t_f = 3 ns)

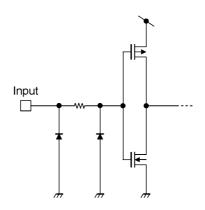
Characteristics	Symbol	Test Condition	V _{CC} (V)	C _L (pF)	Min	Max	Unit
Propagation delay time	t _{PLH} ,t _{PHL}	_	5.0 ± 0.5	15	1.0	7.1	ns
				50	1.0	10.3	
Input capacitance	C _{IN}	_			_	10	pF

9.6. AC Characteristics (Note) (Unless otherwise specified, T_a = -40 to 125 °C, Input: t_r = t_f = 3 ns)

Characteristics	Symbol	Test Condition	V _{CC} (V)	C _L (pF)	Min	Max	Unit
Propagation delay time	t _{PLH} ,t _{PHL}	_	5.0 ± 0.5	15	1.0	8.0	ns
				50	1.0	11.5	
Input capacitance	C _{IN}	_			_	10	pF

Note: For devices with the ordering part number ending in J(CT.

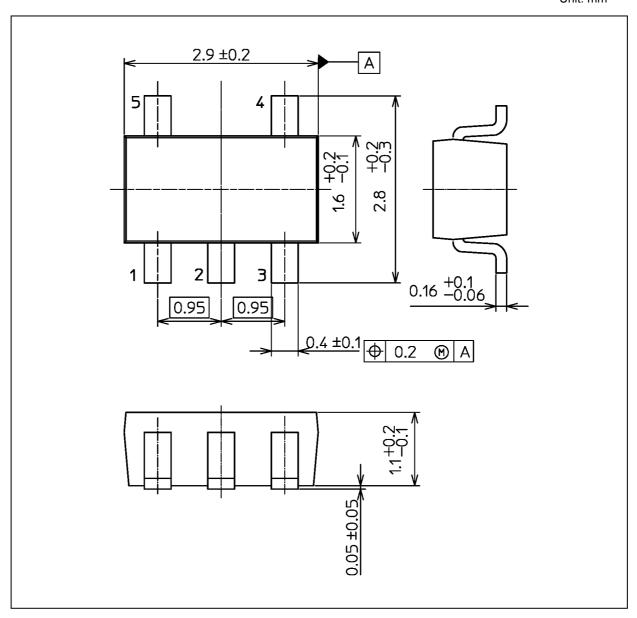
9.7. Internal Equivalent Circuit





Package Dimensions

Unit: mm



Weight: 14 mg (typ.)

	Package Name(s)
JEDEC: SOT-25	
Nickname: SMV	



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